



### PNP SMALL SIGNAL TRANSISTOR IN SOT23

### **Features**

- Ideally Suited for Automatic Insertion
- Complementary NPN Types: BC846 BC848 Family
- For Switching and AF Amplifier Applications
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The BC856AQ BC857BQ are suitable for automotive applications requiring specific change control; these parts are AEC-Q101 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.

https://www.diodes.com/quality/product-definitions/

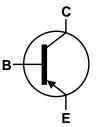
## **Mechanical Data**

- Case: SOT23
- Case Material: Molded Plastic, "Green" Molding Compound.
   UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 (§3)
- Weight: 0.008 grams (Approximate)

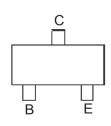




Top View



Device Symbol



Top View Pin-Out

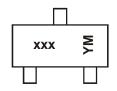
## **Ordering Information** (Note 4)

Part Number	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity Per Reel
BC856AQ-7-F	Automotive	K3A	7	8	3,000
BC856BQ-7-F	Automotive	K3B	7	8	3,000
BC856BQ-13-F	Automotive	K3B	13	8	10,000
BC857BQ-7-F	Automotive	K3B	7	8	3,000

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

## **Marking Information**



xxx = Product Type Marking Code (Please see Ordering Information)

YM = Date Code Marking Y or  $\overline{Y}$  = Year (ex: G = 2019)

M or  $\overline{M}$  = Month (ex: 9 = September)

Date Code Key

Year	2019		2020	2021		2022	2023		2024	2025		2026
Code	G		Н			J	K		L	M		N
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D



## Absolute Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteris	tic	Symbol	Value	Unit
Collector Bose Voltage	BC856	V	-80	V
Collector-Base Voltage	BC857	Vсво	-50	V
Collector-Emitter Voltage	BC856		-65	W
Collector-Emitter Voltage	BC857	VCEO	-45	] v
Emitter-Base Voltage		V <sub>EBO</sub>	-5.0	V
Continuous Collector Current		Ic	-100	mA
Peak Collector Current		Ісм	-200	mA
Peak Emitter Current		ІЕМ	-200	mA
Peak Base Current		Івм	-200	mA

## Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Power Dissipation	(Note 5)	D-	310	mW
Power Dissipation	(Note 6)	P <sub>D</sub>	350	IIIVV
Thermal Decistores, Junction to Ambient	(Note 5)	Б	403	°C/W
Thermal Resistance, Junction to Ambient	(Note 6)	R <sub>0JA</sub>	357	- C/VV
Thermal Resistance, Junction to Leads (Note 7)		Rejl	350	°C/W
Operating and Storage Temperature Range	TJ, TSTG	-65 to +150	°C	

## ESD Ratings (Note 8)

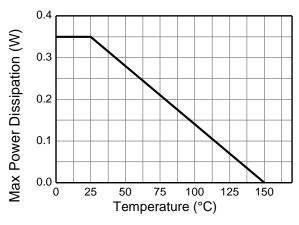
Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

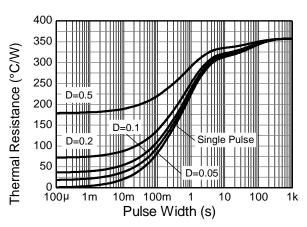
### Notes:

- 5. For a device mounted on minimum recommended pad layout 1oz copper that is on a single-sided FR-4 PCB; device is measured under still air conditions whilst operating in a steady-state.
- 6. Same as note (5), except the device is mounted on 15 mm  $\times$  15mm 1oz copper.
- 7. Thermal resistance from junction to solder-point (at the end of the leads).
  8. Refer to JEDEC specification JESD22-A114 and JESD22-A115.



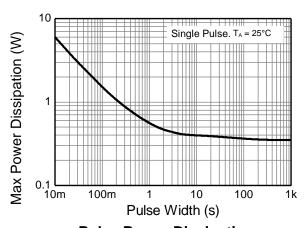
## **Thermal Characteristics and Derating Information**





**Derating Curve** 

**Transient Thermal Impedance** 



**Pulse Power Dissipation** 



# **Electrical Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Ch	aracteristic		Symbol	Min	Тур	Max	Unit	Test Condition
Collector Page Progledown V	Collector-Base Breakdown Voltage		D\/	-80			V	1- 40.4
Collector-base breakdown v	ollage	BC857	ВУсво	-50		_	V	Ic = -10μA
Collector-Emitter Breakdown Voltage		BC856	5)./	-65			V	1 40 4
(Note 9)			BVCEO	-45	T —	_	V	Ic = -10mA
Emitter-Base Breakdown Vol	tage		BVEBO	-5	_	_	V	I <sub>E</sub> = -1μA
Collector Cutoff Current			lana			-15	nA	V <sub>CB</sub> = -30V
Collector Cutoff Current			Ісво	_		-4	μΑ	V <sub>CB</sub> = -30V, T <sub>J</sub> = +150°C
Collector Emitter Cutoff Curre	- n-t	BC856				-15	nA	V <sub>CE</sub> = -80V
Collector Emiller Cuton Cum	eni	BC857	ICES	_	_	-15	nA	Vce = -50V
Emitter-Base Cutoff Current			I <sub>EBO</sub>	_	_	-100	nA	V <sub>EB</sub> = -5V
Small Signal Current Cain	E	3C856A	h.		200			
Small Signal Current Gain	BC856B / BC857B		h <sub>fe</sub>	_	330	_	_	I <sub>C</sub> = -2.0mA, V <sub>CE</sub> = -5V f = 1.0kHz
Input Impedance	BC856A BC856B / BC857B		ь.	_	2.7		kΩ	
input impedance			h <sub>ie</sub>		4.5	_		
Output Admittance	BC856A				18		μS	
Output Admittance	BC856	6B / BC857B	h <sub>oe</sub>	_	30	_	μΟ	
Reverse Voltage Transfer	BC856A			_	1.5x10 <sup>-4</sup>		_	
Ratio	BC856B / BC857B		h <sub>re</sub>		2x10 <sup>-4</sup>	_		
DC Current Cain (Note 0)	BC856A			125	180	250		
DC Current Gain (Note 9)	BC856	6B / BC857B	hFE	220	290	475	_	Ic = -2.0mA, $VcE = -5V$
Collector-Emitter Saturation	Voltago (Noto O		\/ ·		-75	-300	m\/	Ic = -10mA, I <sub>B</sub> = -0.5mA
Collector-Emitter Saturation	voltage (Note 9)	)	VCE(sat)	_	-250	-650	mV	Ic = -100mA, I <sub>B</sub> = -5.0mA
Base-Emitter Turn-On Voltag	io (Noto O)		\/·	-600	-650	-750	mV	Ic = -2mA, VcE = -5V
Base-Emiller Turn-On Vollag	ge (Note 9)		V <sub>BE(on)</sub>	_	_	-820	IIIV	Ic = -10mA, VcE = -5V
Base Emitter Saturation Volt	ago (Noto O)		V-=( )		-700	1	mV	$I_C = -10mA$ , $I_B = -0.5mA$
Base-Emitter Saturation Voltage (Note 9)		V <sub>BE(sat)</sub>	_	-850	-1100	IIIV	$I_C = -100 \text{mA}, I_B = -5 \text{mA}$	
Output Capacitance			Cobo		3	_	pF	V <sub>CB</sub> = -10V, f = 1.0MHz
Transition Frequency			f⊤	100	200	_	MHz	$V_{CE} = -5V, I_{C} = -10mA,$ f = 100MHz
Noise Figure			NF	_	2	10	dB	$\begin{aligned} &\text{Vce} = \text{-5V, lc} = \text{-200}\mu\text{A} \\ &\text{Rs} = 2k\Omega, \text{f} = \text{1kHz} \\ &\Delta \text{f} = 200\text{Hz} \end{aligned}$

Note:

9. Measured under pulsed conditions. Pulse width  $\leq$  300 $\mu$ s. Duty cycle  $\leq$  2%.



## Typical Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

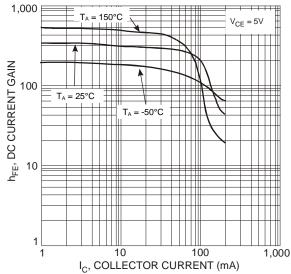
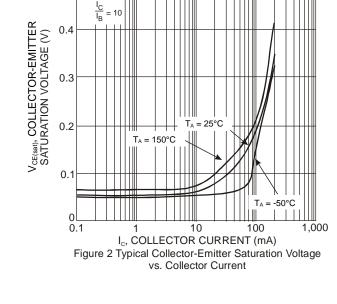


Figure 1 Typical DC Current Gain vs. Collector Current



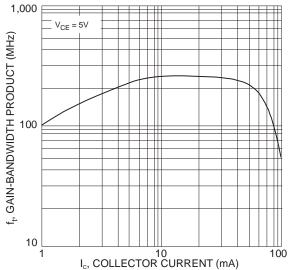


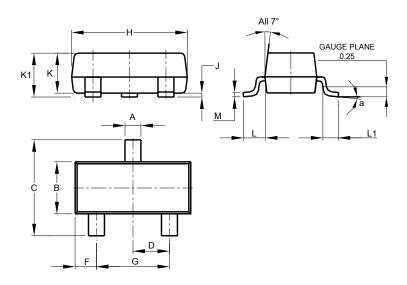
Figure 3 Gain-Bandwidth Product vs Collector Current



## **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

### SOT23

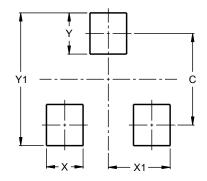


SOT23							
Dim	Min	Max	Тур				
Α	0.37	0.51	0.40				
В	1.20	1.40	1.30				
С	2.30	2.50	2.40				
D	0.89	1.03	0.915				
F	0.45	0.60	0.535				
G	1.78	2.05	1.83				
Н	2.80	3.00	2.90				
J	0.013	0.10	0.05				
K	0.890	1.00	0.975				
K1	0.903	1.10	1.025				
L	0.45	0.61	0.55				
L1	0.25	0.55	0.40				
М	0.085	0.150	0.110				
а	0°	8°					
All	All Dimensions in mm						

## **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

### SOT23



Dimensions	Value (in mm)
С	2.0
X	0.8
X1	1.35
Υ	0.9
Y1	2.9



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